# BLF7G10L-250; BLF7G10LS-250 Power LDMOS transistor

**AMPLEON** 

Rev. 6 — 7 November 2016

Product data sheet

### **Product profile**

#### 1.1 General description

250 W LDMOS power transistor for base station applications at frequencies from 869 MHz to 960 MHz.

#### Table 1. Typical performance

Test signal: 3GPP; test model 1; 64 DPCH; PAR = 7.5 dB at 0.01 % probability on CCDF per carrier; carrier spacing = 5 MHz. Typical RF performance at  $T_{case}$  = 25 °C.

Test signal	f	I <sub>Dq</sub>	V <sub>DS</sub>	P <sub>L(AV)</sub>	Gp	$\eta_D$	ACPR
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)
2-carrier W-CDMA	869 to 894 [1]	1800	30	60	19.5	27.4	-35.6
2-carrier W-CDMA	920 to 960 2	1800	30	60	19.5	30.5	-34

<sup>[1]</sup> In a common source class-AB application test circuit.

#### 1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Designed for broadband operation (869 MHz to 960 MHz)
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use (input and output)
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

#### 1.3 Applications

RF power amplifiers for W-CDMA base stations and multi carrier applications in the 869 MHz to 960 MHz frequency range

<sup>[2]</sup> In a common source class-AB production test circuit.

### 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
BLF7G10L-2	50 (SOT502A)		
1	drain		
2	gate	5 1 3	1 
3	source [1]		2 3 sym112
BLF7G10LS-	250 (SOT502B)		
1	drain		
2	gate	1 3	1 
3	source [1]	2	2 — 3 sym112

<sup>[1]</sup> Connected to flange

### 3. Ordering information

Table 3. Ordering information

Type number	Packag	ackage				
	Name	ame Description				
BLF7G10L-250	-	flanged ceramic package; 2 mounting holes; 2 leads	SOT502A			
BLF7G10LS-250	-	earless flanged ceramic package; 2 leads	SOT502B			

### 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	65	V
$V_{GS}$	gate-source voltage		-0.5	+13	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	200	°C

### 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-c)</sub>	thermal resistance from junction to case	$T_{case}$ = 80 °C; $P_L$ = 60 W (CW); $V_{DS}$ = 30 V; $I_{Dq}$ = 1800 mA	0.38	K/W

#### 6. Characteristics

Table 6. DC characteristics

 $T_i = 25 \, ^{\circ}$ C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V; } I_D = 3.3 \text{ mA}$	65	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 330 A	1.50	1.9	2.30	V
$V_{GSq}$	gate-source quiescent voltage	V <sub>DS</sub> = 30 V; I <sub>D</sub> = 1.8 A	1.63	2.03	2.43	V
I <sub>DSS</sub>	drain leakage current	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 28 V	-	-	5	μА
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	56	-	Α
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 11 V; V <sub>DS</sub> = 0 V	-	-	0.5	mA
g <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 11.55 A	-	22	-	S
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 11.55 A$	-	57	-	mΩ

#### Table 7. RF characteristics

Test signal: 2-carrier W-CDMA; PAR = 7.5 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 64 DPCH;  $f_1$  = 920 MHz;  $f_2$  = 925 MHz;  $f_3$  = 955 MHz;  $f_4$  = 960 MHz; RF performance at  $V_{DS}$  = 30 V;  $I_{Dq}$  = 1800 mA;  $T_{case}$  = 25 °C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P <sub>L(AV)</sub> = 60 W	18.5	19.5	-	dB
RLin	input return loss	P <sub>L(AV)</sub> = 60 W	-	-15.5	-10	dB
$\eta_{D}$	drain efficiency	P <sub>L(AV)</sub> = 60 W	27	30.5	-	%
ACPR	adjacent channel power ratio	P <sub>L(AV)</sub> = 60 W	-	-34	-31	dBc

#### 7. Test information

#### 7.1 Ruggedness in class-AB operation

The BLF7G10L-250 and BLF7G10LS-250 are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS} = 30 \text{ V}$ ;  $I_{Dq} = 1800 \text{ mA}$ ;  $P_L = 200 \text{ W}$  (CW); f = 920 MHz to 960 MHz.

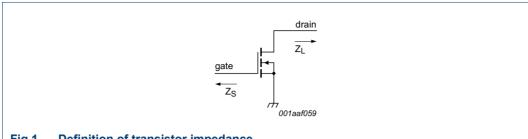
#### 7.2 Impedance information

Table 8. Typical impedance information

 $I_{Dq}$  = 1800 mA; main transistor  $V_{DS}$  = 30 V.

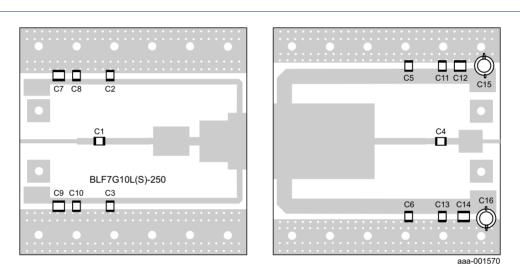
 $Z_S$  and  $Z_L$  defined in <u>Figure 1</u>.

f	Z <sub>S</sub>	$Z_L$
(MHz)	(Ω)	(Ω)
925	3.1 – j3.3	1.0 – j1.7
942	3.2 – j3.3	1.0 – j1.6
960	3.4 – j3.5	0.9 – j1.4



**Definition of transistor impedance** 

#### 7.3 Circuit



Printed-Circuit Board (PCB): Rogers RO3006;  $\varepsilon_r$  = 6.15 F/m; thickness = 0.635 mm; thickness copper plating = 35  $\mu$ m.

The vias can be used as a reference to place components.

The above layout shows the test circuit used to measure the devices in production. A more appropriate application demonstration for specific customer needs can be provided.

See Table 9 for list of components.

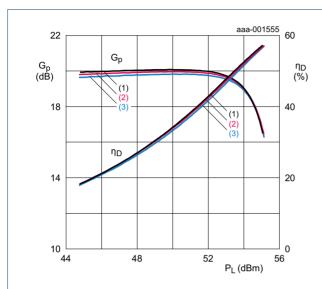
#### Fig 2. **Component layout**

List of components See Figure 2 for component layout.

Component	Description	Value	Remarks
C1, C2, C3, C4, C5, C6	multilayer ceramic chip capacitor	82 pF	ATC800B
C7, C9, C12, C14	multilayer ceramic chip capacitor	10 μF	Murata
C8, C10, C11, C13	multilayer ceramic chip capacitor	1 μF	Murata
C15, C16	electrolytic capacitor	470 μF, 63 V	

#### 7.4 Graphs

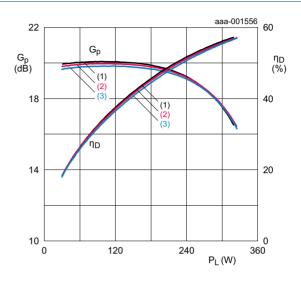
#### 7.4.1 CW pulsed



 $V_{DS}$  = 30 V;  $I_{Dq}$  = 1800 mA.

- (1) f = 920 MHz
- (2) f = 940 MHz
- (3) f = 960 MHz

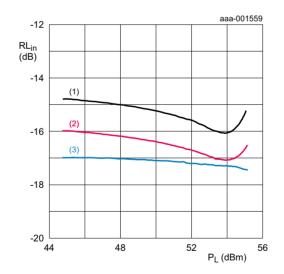




 $V_{DS}$  = 30 V;  $I_{Dq}$  = 1800 mA.

- (1) f = 920 MHz
- (2) f = 940 MHz
- (3) f = 960 MHz

Fig 4. Power gain and drain efficiency as function of output power; typical values

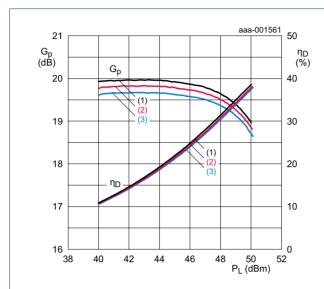


 $V_{DS} = 30 \text{ V}; I_{Dq} = 1800 \text{ mA}.$ 

- (1) f = 920 MHz
- (2) f = 940 MHz
- (3) f = 960 MHz

Fig 5. Input return loss as a function of output power; typical values

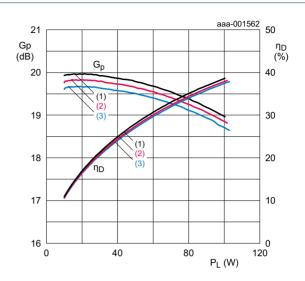
#### 7.4.2 2-Carrier W-CDMA



 $V_{DS} = 30 \text{ V}; I_{Dq} = 1800 \text{ mA}.$ 

- (1) f = 920 MHz
- (2) f = 940 MHz
- (3) f = 960 MHz

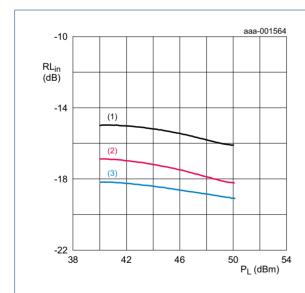
Fig 6. Power gain and drain efficiency as function of output power; typical values



 $V_{DS} = 30 \text{ V}; I_{Da} = 1800 \text{ mA}.$ 

- (1) f = 920 MHz
- (2) f = 940 MHz
- (3) f = 960 MHz

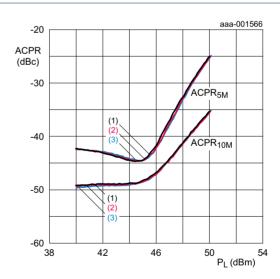
Fig 7. Power gain and drain efficiency as function of output power; typical values



 $V_{DS} = 30 \text{ V}; I_{Dq} = 1800 \text{ mA}.$ 

- (1) f = 920 MHz
- (2) f = 940 MHz
- (3) f = 960 MHz

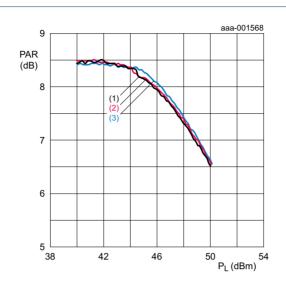
Fig 8. Input return loss as a function of output power; typical values



 $V_{DS}$  = 30 V;  $I_{Dq}$  = 1800 mA.

- (1) f = 920 MHz
- (2) f = 940 MHz
- (3) f = 960 MHz

Fig 9. Adjacent channel power ratio (5 MHz and 10 MHz) as function of output power; typical values

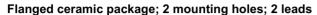


 $V_{DS}$  = 30 V;  $I_{Dq}$  = 1800 mA.

- (1) f = 920 MHz
- (2) f = 940 MHz
- (3) f = 960 MHz

Fig 10. Peak-to-average ratio as a function of output power; typical values

### 8. Package outline



SOT502A

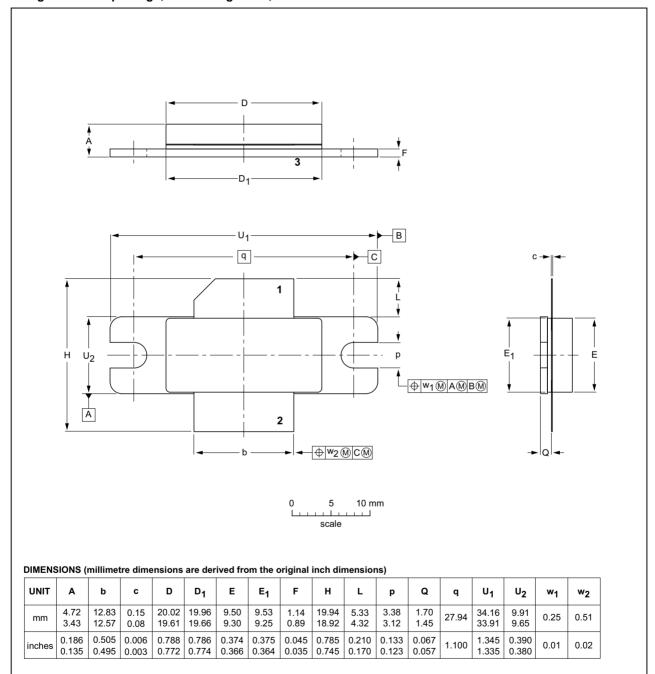


Fig 11. Package outline SOT502A

**JEDEC** 

IEC

OUTLINE

VERSION

SOT502A

JEITA

REFERENCES

**ISSUE DATE** 

03-01-10

12-05-02

EUROPEAN

**PROJECTION** 

#### Earless flanged ceramic package; 2 leads

SOT502B

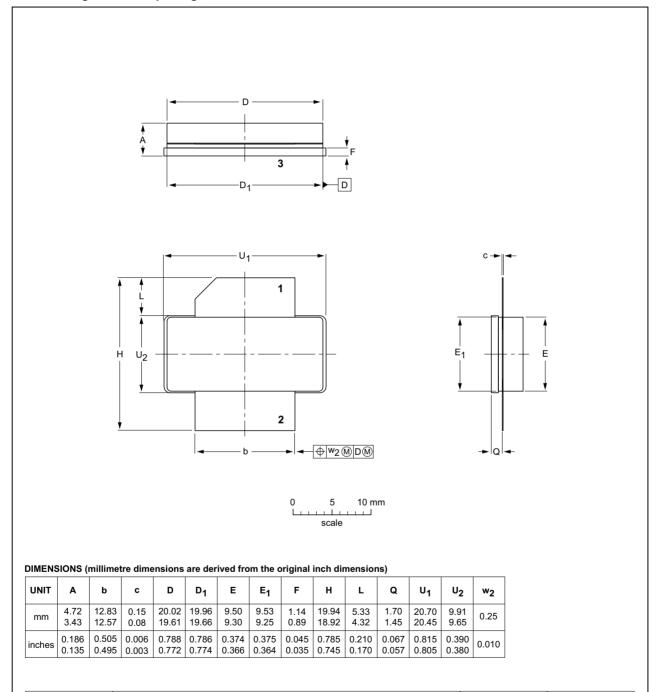


Fig 12. Package outline SOT502B

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OUTLINE

VERSION

SOT502B

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**REFERENCES** 

**JEDEC** 

**ISSUE DATE** 

07-05-09

12-05-02

EUROPEAN

**PROJECTION** 

### 9. Handling information

#### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

### 10. Abbreviations

Table 10. Abbreviations

Acronym	Description	
3GPP	Third Generation Partnership Project	
CCDF	Complementary Cumulative Distribution Function	
CW	ontinuous Wave	
DPCH	Dedicated Physical CHannel	
ESD	ElectroStatic Discharge	
LDMOS	aterally Diffused Metal Oxide Semiconductor	
PAR	Peak-to-Average Ratio	
VSWR	oltage Standing Wave Ratio	
W-CDMA	Wideband Code Division Multiple Access	

### 11. Revision history

Table 11. Revision history

Document ID	Release date		Change notice	Supersedes
BLF7G10L-250_7G10LS-250 v.6	20161107	Product data sheet	-	BLF7G10L-250_7G10LS-250 v.5
Modifications:	Table 6 on	page 3: added V <sub>GSq</sub> pa	rameter to table	•
BLF7G10L-250_7G10LS-250 v.5	20150901	Product data sheet	-	BLF7G10L-250_7G10LS-250 v.4
BLF7G10L-250_7G10LS-250 v.4	20120913	Product data sheet	-	BLF7G10L-250_7G10LS-250 v.3
BLF7G10L-250_7G10LS-250 v.3	20120216	Product data sheet	-	BLF7G10L-250_7G10LS-250 v.2
BLF7G10L-250_7G10LS-250 v.2	20111114	Preliminary data sheet	-	BLF7G10L-250_7G10LS-250 v.1
BLF7G10L-250_7G10LS-250 v.1	20110225	Objective data sheet	-	-

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Document status[1][2]	Product status[3]	Definition		
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.		
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Product [short] data sheet	Production	This document contains the product specification.		

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**Power LDMOS transistor** 

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## BLF7G10L-250; BLF7G10LS-250

### **AMPLEON**

**Power LDMOS transistor** 

### 14. Contents

1	Product profile
1.1	General description
1.2	Features and benefits
1.3	Applications
2	Pinning information
3	Ordering information
4	Limiting values
5	Thermal characteristics
6	Characteristics
7	Test information 3
7.1	Ruggedness in class-AB operation 3
7.2	Impedance information
7.3	Circuit
7.4	Graphs
7.4.1	CW pulsed 5
7.4.2	2-Carrier W-CDMA 6
8	Package outline
9	Handling information
10	Abbreviations
11	Revision history
12	Legal information
12.1	Data sheet status
12.2	Definitions
12.3	Disclaimers
12.4	Trademarks12
13	Contact information
14	Contents

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